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Transport Parallel to QW; 10.3 Magnetic Response
 10.4 Concepts of Electric Conductivity 10.5 Universal Conductance
 Fluctuation; 10.6 Quantized Conductance; 10.7 Integral Quantized Hall
 Effect (IQHE); 10.8 Fractional Quantized Hall Effect (FQHE); 10.9 Ballistic
 Transport; 10.10 Coulomb Blockade; 10.11 Atomic Wires; References;
 11 Optical Properties; 11.1 Single/Multiple Quantum Wells; 11.2
 Exciton Absorption in Various Dimensional Geometries; References; 12
 Magnetic Properties; 12.1 Fine Particles; 12.2 Magnetic Thin Films;
 References; 13 Properties of Macroscopic Quantum States; 13.1
 Kosterlitz-Thouless Mode in High-T_c SC
 13.2 Superconducting Thin Wires 13.3 Superconducting Tunnel
 Junction; 13.4 Transport Properties of High-T_c, Cuprates; 13.5
 Proximity Effect; 13.6 Andreev Reflection; References; 14 Future
 Prospects; Appendix A FDM Solution of Schrodinger Equations;
 Appendix B Effective-Mass Approximated Equation; Appendix C
 Boundary Conditions for an Interface; Appendix D Hydrogenic Envelope
 Function in 3D and 2D; Appendix E Transition Probability of Optical
 Processes; Appendix F Eigenvalue Problem for a Linear Electric
 Potential; Appendix G Calculation of Conductivity Based on the Kubo
 Formula
 Appendix H Calculation of Conductivity Tensor in a Magnetic
 Field Appendix I Landau State in z-Representation; Appendix J
 Micromagnetism of Stripe Domain; Appendix K Physics Underlying
 Josephson Junctions; Index; Author Index

Sommario/riassunto

Future high-tech applications such as nanotechnology require a deep understanding of the physics of mesoscopic systems. These systems form a bridge between macroscopic systems governed by classical physics and microscopic systems governed by quantum physics. This introduction discusses a variety of typical surface, optical, transport, and magnetic properties of mesoscopic systems with reference to many experimental observations. It is written for physicists, materials scientists and engineers who want to stay abreast of current research or high-tech development.
